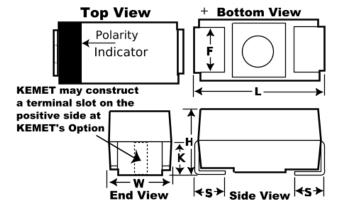


T498X106M050ZTE500

B45196P, Tantalum, MnO2 Tantalum, High Temperature, 10 uF, 20%, 50 VDC, SMD, Molded, High Temperature, N/A, 500 mOhms, 7343, Height Max = 4.4mm



Dimensions	
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	4.1mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
К	1.8mm TYP

Packaging Specifications		
Packaging	T&R, 178mm	
Packaging Quantity	400	

General Information		
Series	B45196P	
Dielectric	MnO2 Tantalum	
Style	SMD Chip	
Description	SMD, Molded, High Temperature	
Features	High Temperature	
RoHS	Yes	
Termination	Tin	
AEC-Q200	No	
Notes	Obsolete. Old Part Number [Obsolete] Was B45196P7106M509.	

Specifications	
Capacitance	10 uF
Capacitance Tolerance	20%
Voltage DC	50 VDC (85C), 39.85 VDC (125C), 33.5 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5%
Failure Rate	N/A
Resistance	0.5 Ohms (100kHz)
Leakage Current	5 uA

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.